



SPECIFICATION

• Supplier : Samsung electro-mechanics • Samsung P/N : CL21X476MRYNNNE

• Product : Multi-layer Ceramic Capacitor • Description : CAP, 47 µF, 4V, ±20%, X6S, 0805

A. Samsung Part Number

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① Series	Samsung Multi-layer Ceramic Capacitor		
② Size	0805 (inch code)	L: 2.0 ± 0.2 mm	W: 1.25 ± 0.2 mm
© Dialogánia	VCC	O longer electrode	NI:
3 Dielectric	X6S	8 Inner electrode	Ni
4 Capacitance	47 μF	Termination	Cu
⑤ Capacitance	±20 %	Plating	Sn 100% (Pb Free)
tolerance		Product	Normal
6 Rated Voltage	4 V	Special	Reserved for future use
7 Thickness	1.25 ± 0.2 mm	Packaging	Embossed Type, 7" reel

B. Samsung Reliability Test and Judgement condition

	Performance	Test condition	
Capacitance	Within specified tolerance	120Hz ±20% 0.5±0.1Vrms	
Tan δ (DF)	0.1 max.		
Insulation	10,000Mohm or 100Mohm⋅µF	Rated Voltage 60~120 sec.	
Resistance	Whichever is Smaller		
Appearance	No abnormal exterior appearance	Microscope (×10)	
Withstanding	No dielectric breakdown or	250% of the rated voltage	
Voltage	mechanical breakdown		
Temperature	X6S		
Characteristics	(From -55℃ to 105℃, Capacitance change should be within ±22%)		
Adhesive Strength	No peeling shall be occur on the	500g·F, for 10±1 sec.	
of Termination	terminal electrode		
Bending Strength	Capacitance change: within ±12.5%	Bending to the limit (1mm)	
		with 1.0mm/sec.	
Solderability	More than 75% of terminal surface	SnAg3.0Cu0.5 solder	
	is to be soldered newly	245±5℃, 3±0.3sec.	
		(preheating : 80~120 ℃ for 10~30sec.)	
Resistance to	Capacitance change: within ±7.5%	Solder pot : 270±5℃, 10±1sec.	
Soldering heat	Tan δ, IR : initial spec.		

	Performance	Test condition
Vibration Test	Capacitance change: within ±10%	Amplitude : 1.5mm
	Tan δ, IR : initial spec.	From 10Hz to 55Hz (return : 1min.)
		2hours × 3 direction (x, y, z)
Moisture	Capacitance change: within ±12.5%	With rated voltage
Resistance	Tan δ : 0.2 max	40±2℃, 90~95%RH, 500+12/-0hrs
	IR: $12.5 \text{M}\Omega \cdot \mu \text{F}$ or Over	
High Temperature	Capacitance change: within ±12.5%	With 100% of the rated voltage
Resistance	Tan δ: 0.2 max	Max. operating temperature
	IR: 25MΩ·μF or Over	
		1000+48/-0hrs
Temperature	Capacitance change : within ±15%	1 cycle condition
Cycling	Tan δ, IR : initial spec.	Min. operating temperature → 25 °C
		$ ightarrow$ Max. operating temperature $ ightarrow$ 25 $^{\circ}$ C
		5 cycle test

C. Recommended Soldering method :

Reflow (Reflow Peak Temperature : 260+0/-5 $^{\circ}$ C, 10sec. Max)

^{*} For the more detail Specification, Please refer to the Samsung MLCC catalogue.